



Product Description

The S10040340 is a Hybrid Push Pull amplifier module. The part employs GaAs die and is operated from 40MHz to 1GHz. It provides excellent linearity and superior return loss performance with low noise and optimal reliability.

Features

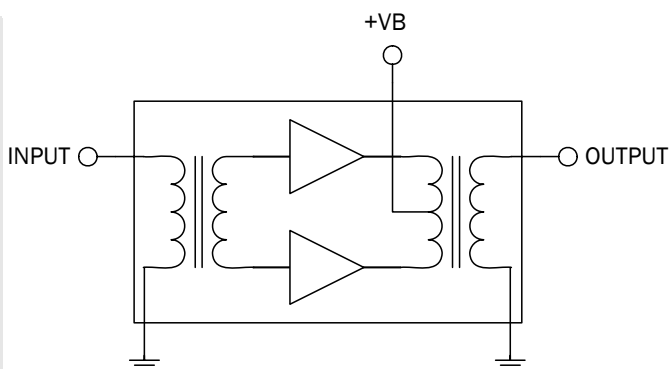
- Excellent Linearity
- Superior Return Loss Performance
- Extremely Low Distortion
- Optimal Reliability
- Extremely Low Noise
- Unconditionally Stable Under All Terminations
- 34.5dB Min. Gain at 1GHz
- 280mA Max. at 24VDC

Applications

- 40MHz to 1GHz CATV Amplifier Systems

Optimum Technology Matching® Applied

- GaAs HBT
- GaAs MESFET
- InGaP HBT
- SiGe BiCMOS
- Si BiCMOS
- SiGe HBT
- GaAs pHEMT
- Si CMOS
- Si BJT
- GaN HEMT
- RF MEMS



Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
Overall					$V_B = 24V; T_{MB} = 30^\circ C; Z_S = Z_L = 75\Omega$
Power Gain		34.0		dB	$f = 50MHz$
	34.5		36.5	dB	$f = 1000MHz$
Slope [1]	0.5	1.5	2.5	dB	$f = 40MHz$ to $1000MHz$
Flatness of Frequency Response			1.0	dB	$f = 40MHz$ to $1000MHz$
Input Return Loss	20.0			dB	$f = 40MHz$ to $160MHz$
	17.0			dB	$f = 160MHz$ to $870MHz$
	16.0			dB	$f = 870MHz$ to $1000MHz$
Output Return Loss	20.0			dB	$f = 40MHz$ to $160MHz$
	17.0			dB	$f = 160MHz$ to $870MHz$
	16.0			dB	$f = 870MHz$ to $1000MHz$
Noise Figure			4.5	dB	$f = 50MHz$ to $1000MHz$
Total Current Consumption (DC)		240.0	280.0	mA	
Distortion data 40MHz to 750MHz					
CTB		-66	-64	dBc	112 ch flat; $V_0 = 44 dBmV^{[2]}$
XMOD		-60	-58	dBc	112 ch flat; $V_0 = 44 dBmV^{[2]}$
CSO		-65	-63	dBc	112 ch flat; $V_0 = 44 dBmV^{[2]}$

1. The slope is defined as the difference between the gain at the start frequency and the gain at the stop frequency.
 2. 112 channels, NTSC frequency raster: 55.25MHz to 745.25MHz, +44 dBmV flat output level.
 Composite Second Order (CSO) - The CSO parameter (both sum and difference products) is defined by the NCTA.
 Composite Triple Beat (CTB) - The CTB parameter is defined by the NCTA.
 Cross Modulation (XMOD) - Cross modulation (XMOD) is measured at baseband (selective voltmeter method), referenced to 100% modulation of the carrier being tested.

Absolute Maximum Ratings

Parameter	Rating	Unit
RF Input Voltage (single tone)	75	dBmV
DC Supply Over-Voltage (5 minutes)	30	V
Storage Temperature	-40 to +100	°C
Operating Mounting Base Temperature	-30 to +100	°C

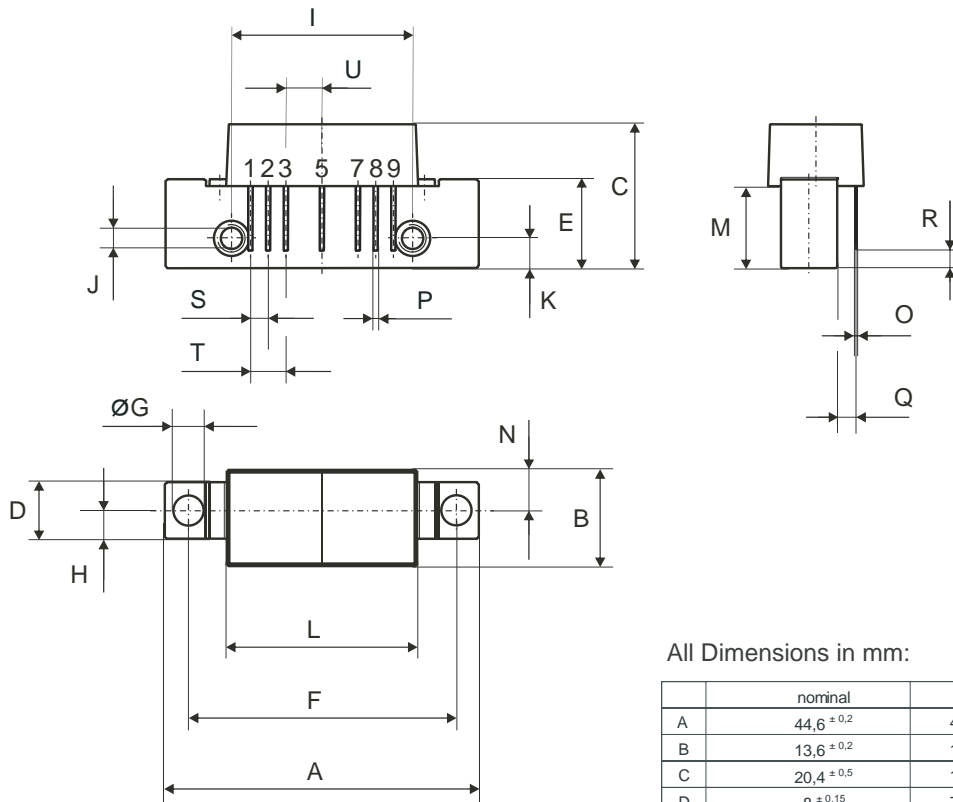


Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EU Directive 2002/95/EC (at time of this document revision).

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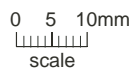


All Dimensions in mm:

	nominal	min	max
A	44,6 ^{+0,2}	44,4	44,8
B	13,6 ^{+0,2}	13,4	13,8
C	20,4 ^{+0,5}	19,9	20,9
D	8 ^{+0,15}	7,85	8,15
E	12,6 ^{+0,15}	12,45	12,75
F	38,1 ^{+0,2}	37,9	38,3
G	4 ^{+0,2/-0,05}	3,95	4,2
H	4 ^{+0,2}	3,8	4,2
I	25,4 ^{+0,2}	25,2	25,6
J	UNC 6-32	-	-
K	4,2 ^{+0,2}	4,0	4,4
L	27,2 ^{+0,2}	27,0	27,4
M	11,6 ^{+0,5}	11,1	12,1
N	5,8 ^{+0,4}	5,4	6,2
O	0,25 ^{+0,02}	0,23	0,27
P	0,45 ^{+0,03}	0,42	0,48
Q	2,54 ^{+0,3}	2,24	2,84
R	2,54 ^{+0,5}	2,04	3,04
S	2,54 ^{+0,25}	2,29	2,79
T	5,08 ^{+0,25}	4,83	5,33
U	5,08 ^{+0,25}	4,83	5,33

Pinning:

1	2	3	4	5	6	7	8	9
INPUT	GND	GND	+VB	GND	GND	GND	GND	OUTPUT



Notes:

